

**LA4700N****2-Channel 12W AF Power Amplifier for Car Stereos****Functions**

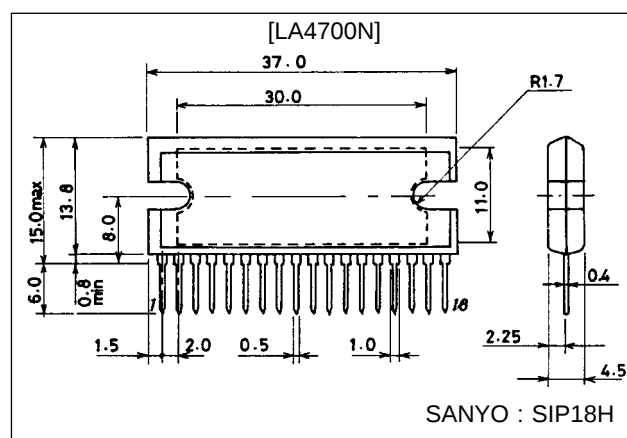
- Standby switch function built in
- Pop noise suppressor built in
- Thermal shutdown circuit built in
- Overvoltage/surge protector built in
- Output pin-to-GND short protector built in
- Output pin-to- V_{CC} short protector built in
- Load short protector built in

Features

- Low pop noise at the time of power supply ON/OFF
- Excellent oscillation stability

Package Dimensions

unit : mm

3109-SIP18H**Specifications****Maximum Ratings at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC} max1	Quiescent $t = 30$ s	26	V
	V_{CC} max2	Quiescent	18	V
	V_{CC} max3	Operating	16	V
Surge supply voltage	V_{CC} surge	$t = 200$ ms rise time 1 ms	50	V
Maximum output current	I_o peak	Per channel	4	A
Allowable power dissipation	P_d max	*Note	37.5	W
Operating temperature	T_{opr}		-30 to $+75$	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to $+150$	$^\circ\text{C}$

Operating Conditions at $T_a = 25^\circ\text{C}$

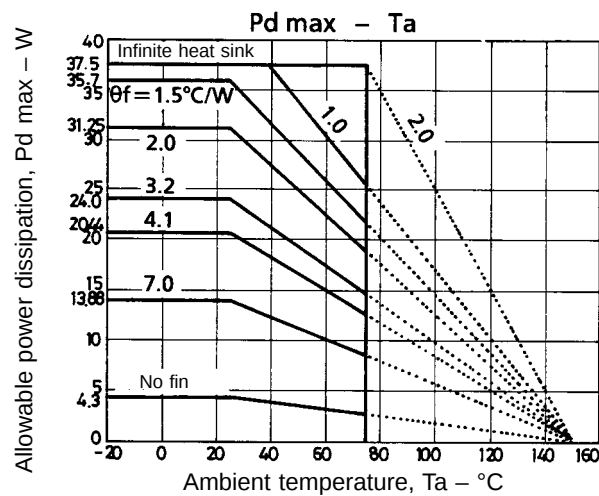
Parameter	Symbol	Conditions	Ratings	Unit
Recommended operating voltage	V_{CC}		13.2	V
Operating voltage range	V_{CC} op		10 to 16	V
Recommended load resistance	R_L	BTL/2ch	4 to 8	Ω

*Note: Use flat head screws for attaching heat sink with tightening torque 39 to 59 N·cm.

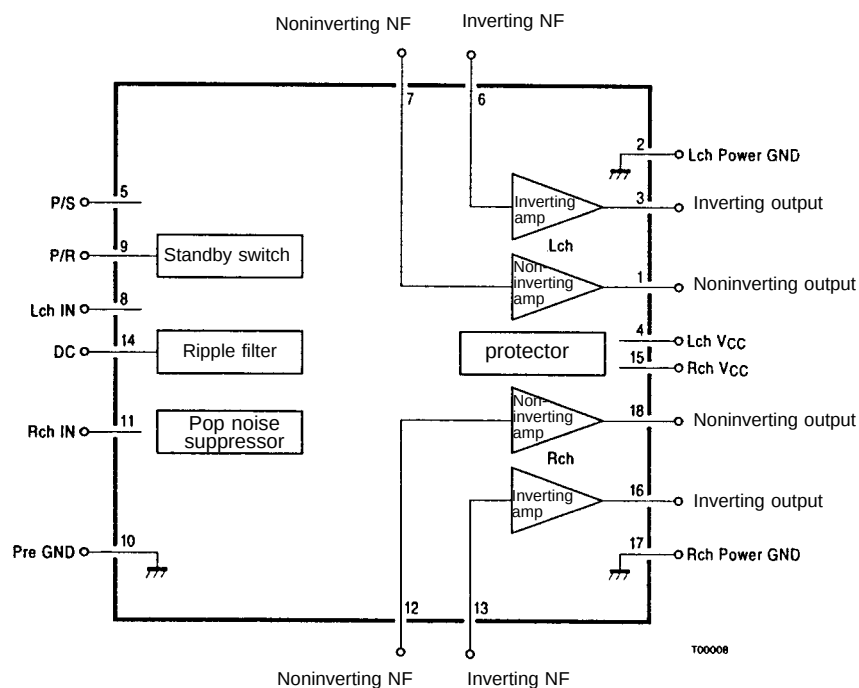
LA4700N

Operating Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 13.2\text{ V}$, $R_L = 4\ \Omega$, $f = 1\text{ kHz}$, $R_g = 600\ \Omega$,
See specified Test Circuit

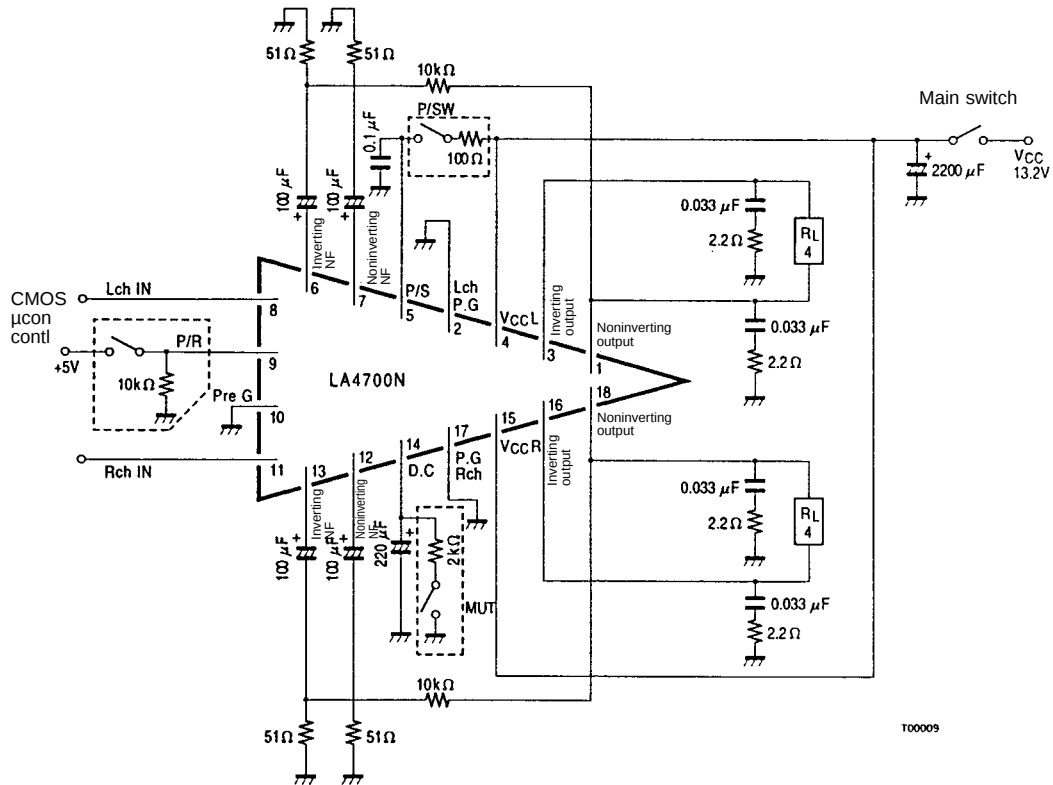
Parameter	Symbol	Conditions	min	typ	max	Unit
Quiescent current	I_{CCO}		60	140	200	mA
Voltage gain	VG		48	50	52	dB
Voltage gain difference	ΔVG				2	dB
Total harmonic distortion	THD	$P_o = 1\text{ W}$		0.15	0.75	%
Output voltage	P_o	THD = 10%	10	12		W
Output noise voltage	V_{NO}	$R_g = 0$, B.P.F. = 20 Hz to 20 kHz		0.2	0.4	mV
Ripple rejection	SVRR	$V_r = 0\text{ dBm}$, $f_R = 100\text{ Hz}$, $R_g = 0$	40	55		dB
Channel separation	CHsep	$P_o = 1\text{ W}$, $R_g = 10\text{ k}\Omega$	50	60		dB
Standby current	1st			10	100	μA
Offset voltage	V_{off}		-300		300	mV



Equivalent Circuit Block Diagram

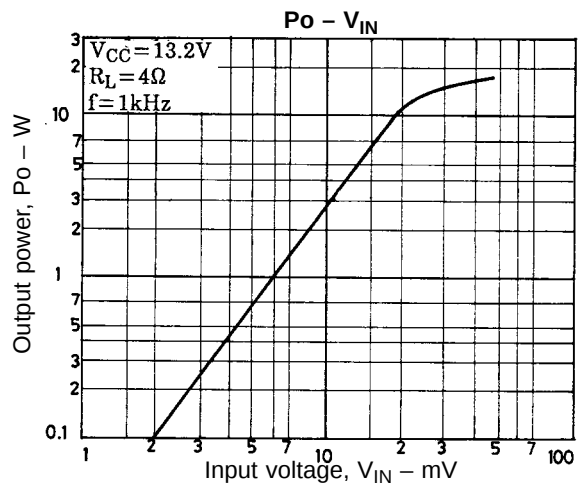
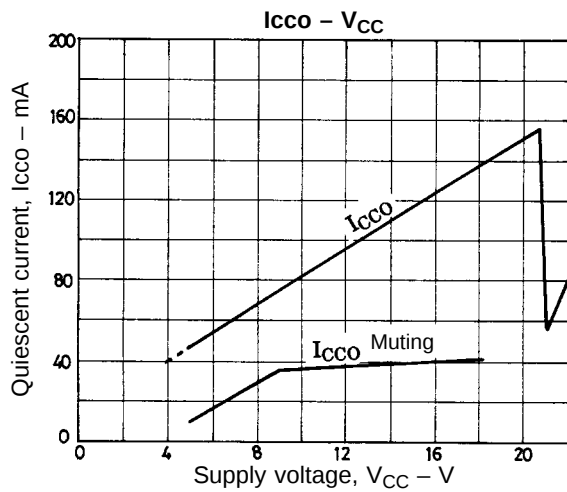


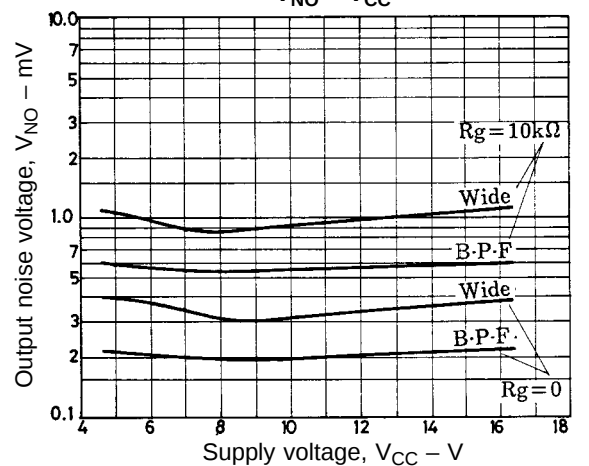
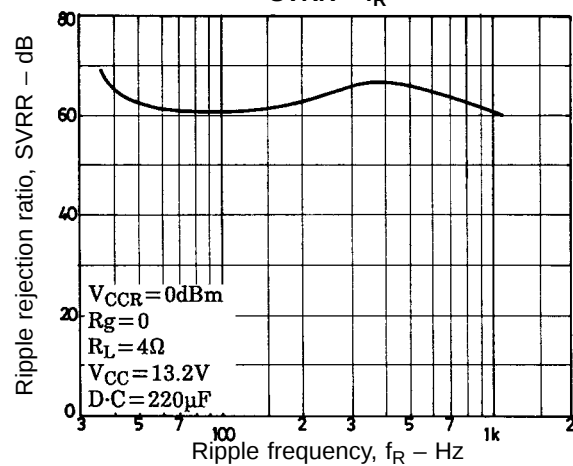
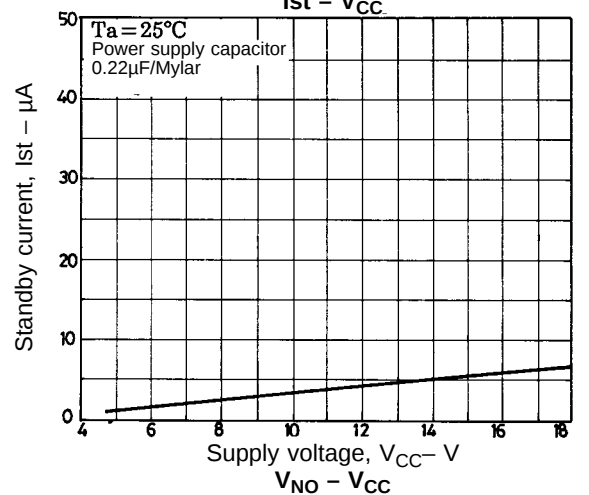
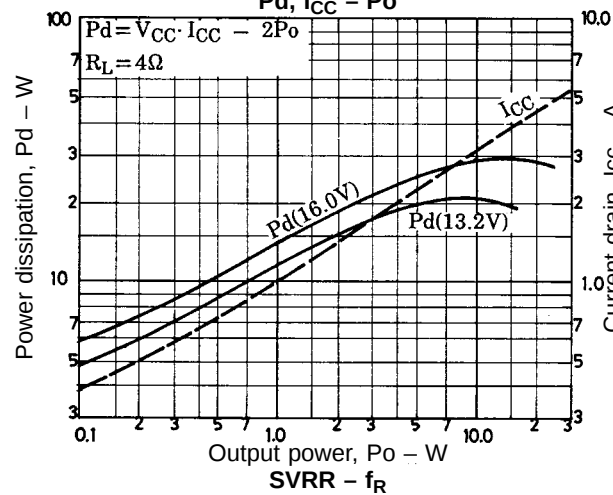
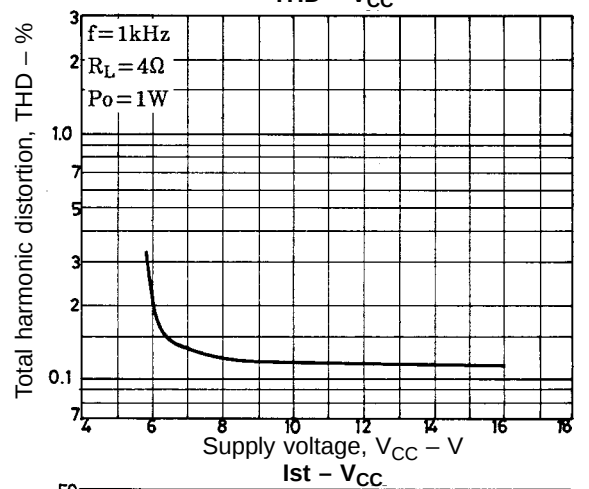
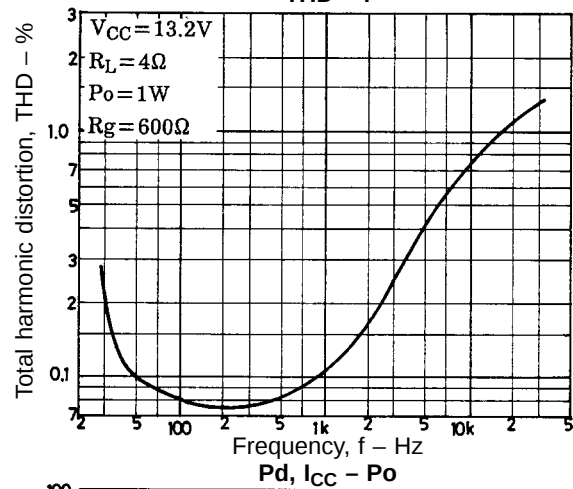
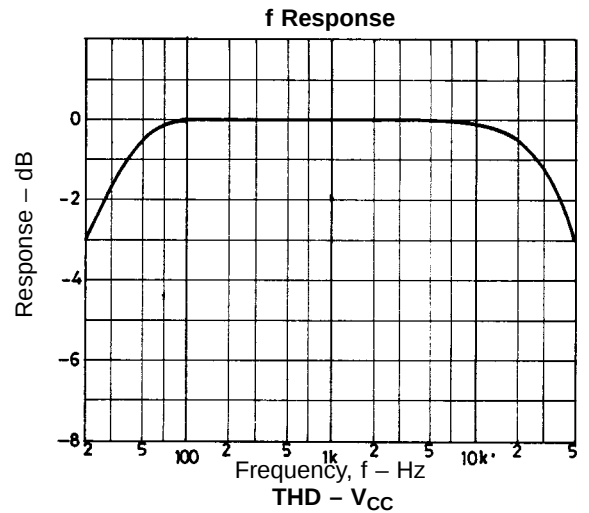
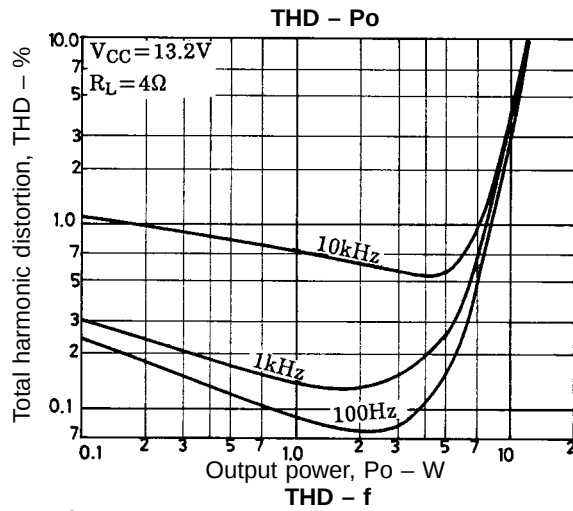
Sample Application Circuit

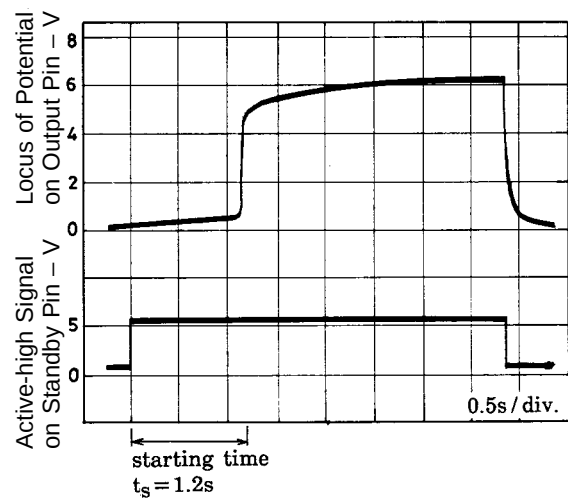
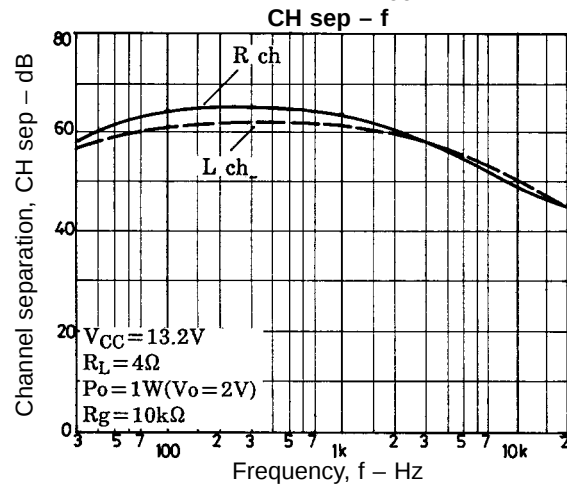
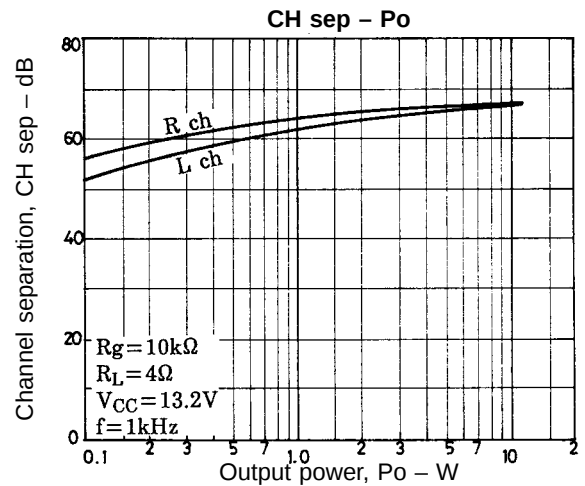
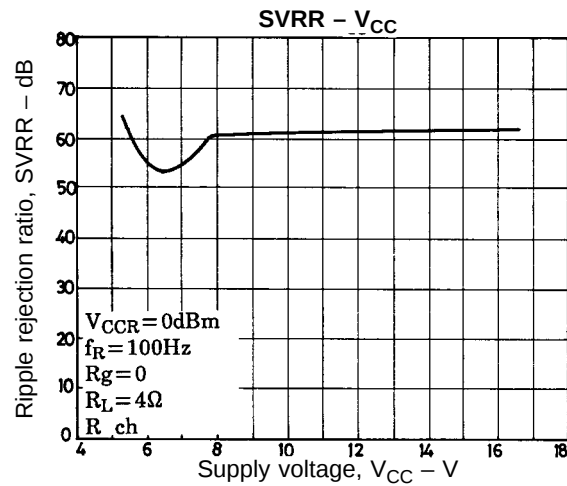


* Connect the portion bounded by a dotted line according to your intended applications.

When the power relay is not used, connect pin ⑨ to GND. In this case, the power switch is used to turn ON/OFF the LA4700N or the main switch is used to turn ON/OFF the LA4700N.







To shorten t_s in the application herein, the filter capacitor (pin 14) value 220 μF is decreased. Filter capacitor value 100 μF gives t_s of 0.6 to 0.7 second.

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